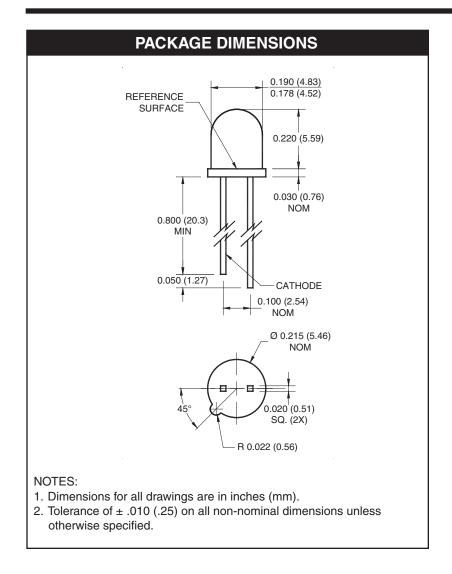
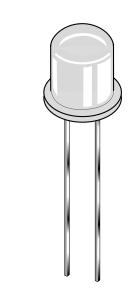
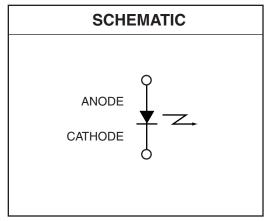


### **QED522 QED523**







### **DESCRIPTION**

The QED522/523 is an 880 nm AlGaAs LED encapsulated in a clear, peach tinted, plastic TO-46 package.

#### **FEATURES**

- $\lambda = 880 \text{ nm}$
- Chip material = AlGaAs
- Package type: Plastic TO-46
- Matched Photosensor: QSD722/723/724
- Narrow Emission Angle, 20°
- · High Output Power
- · Package material and color: clear, peach tinted, plastic



### **QED522 QED523**

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise specified)								
Parameter	Symbol Rating		Unit					
Operating Temperature	T <sub>OPR</sub>	-40 to + 100	°C					
Storage Temperature	T <sub>STG</sub>	-40 to + 100	°C					
Soldering Temperature (Iron) <sup>(2,3,4)</sup>	T <sub>SOL-I</sub>	240 for 5 sec	°C					
Soldering Temperature (Flow) <sup>(2,3)</sup>	T <sub>SOL-F</sub>	260 for 10 sec	°C					
Continuous Forward Current	I <sub>F</sub>	100	mA					
Reverse Voltage	V <sub>R</sub>	5	V					
Power Dissipation <sup>(1)</sup>	P <sub>D</sub>	200	mW					

#### **NOTES:**

- 1. Derate power dissipation linearly 2.67 mW/°C above 25°C.
- 2. RMA flux is recommended.
- 3. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 4. Soldering iron 1/16" (1.6 mm) minimum from housing

ELECTRICAL / OPTICAL CHARACTERISTICS (T <sub>A</sub> =25°C)								
Parameter	Test Conditions	Symbol	Min	Тур	Max	Units		
Peak Emission Wavelength	I <sub>F</sub> = 100 mA	λ <sub>PE</sub>	_	880	_	nm		
Emission Angle	I <sub>F</sub> = 100 mA	2Θ1/2	_	20	_	Deg.		
Forward Voltage	$I_F = 100 \text{ mA}, \text{ tp} = 20 \text{ ms}$	V <sub>F</sub>	_	_	1.8	V		
Reverse Current	V <sub>R</sub> = 5 V	I <sub>R</sub>	_	_	10	μΑ		
Radiant Intensity QEC522	$I_F = 100 \text{ mA}, \text{ tp} = 20 \text{ ms}$	Ι <sub>Ε</sub>	20	_	80	mW/sr		
Radiant Intensity QEC523	$I_F = 100 \text{ mA}, \text{ tp} = 20 \text{ ms}$	Ι <sub>Ε</sub>	40	_	_	mW/sr		
Rise Time	I <sub>F</sub> = 100 mA	t <sub>r</sub>	_	800	_	ns		
Fall Time		t <sub>f</sub>		800	_	ns		



### **QED522 QED523**

Fig. 1 Normalized Radiant Intensity vs. Forward Current

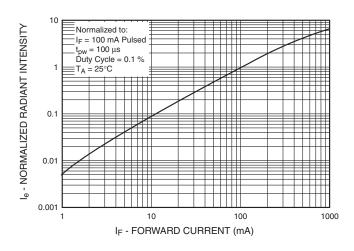


Fig. 2 Forward Voltage vs. Ambient Temperature

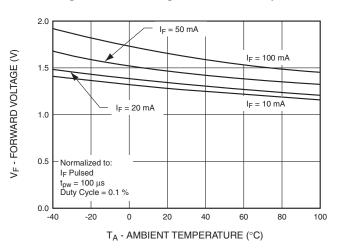


Fig. 3 Normalized Radiant Intensity vs. Wavelength

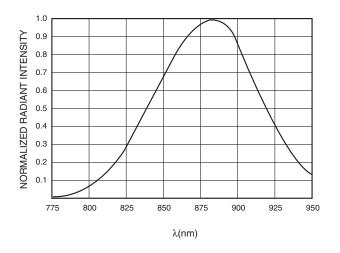
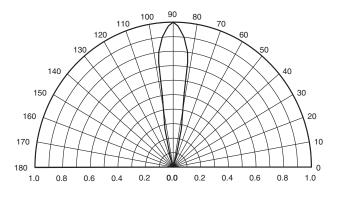


Fig. 4 Radiation Diagram





**QED522 QED523** 

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- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.